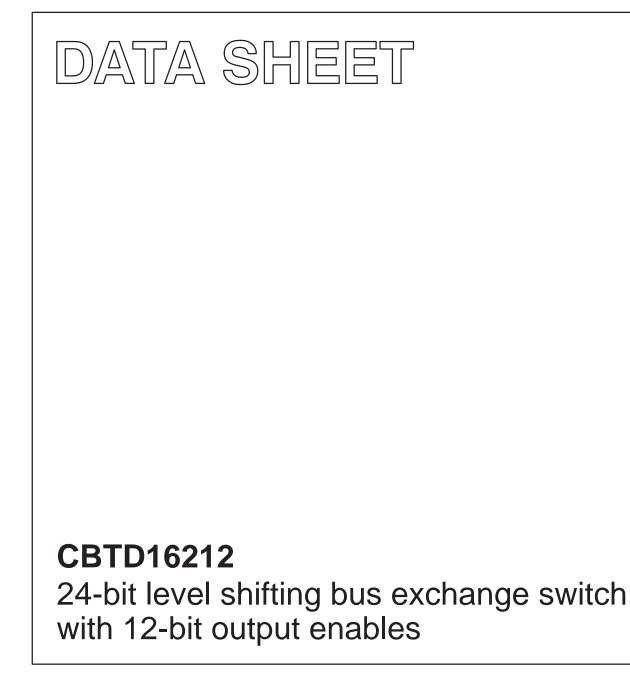
INTEGRATED CIRCUITS



Product data

2001 Sep 28

File under Integrated Ciruits ICL03





CBTD16212

FEATURES

- 5 Ω switch connection between two ports
- TTL compatible control input levels
- Designed to be used in level shifting applications
- Latch-up testing is done to JESDEC Standard JESD78 which exceeds 100 mA
- ESD protection exceeds 1500 V HBM per JESD22-114A and 1000 V CDM per JESD22-C101

DESCRIPTION

The CBTD16212 provides 24 bits of high-speed TTL-compatible bus switching or exchanging. The low on-state resistance of the switch allows connections to be made with minimal propagation delay.

A diode to V_{CC} is integrated into the circuit to allow for level shifting between 5 V inputs and 3.3 V outputs.

The CBTD16212 operates as 24-bit bus switch or a 12-bit bus exchanger, which provides data exchanging between the four signal ports via the data-select (S0–S2) terminals.

The CBT16212 is characterized for operation from -40 to +85 °C.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25 °C; GND = 0 V	TYPICAL	UNIT
t _{pd}	Propagation delay An to Bn	C _L = 50 pF; V _{CC} = 5 V	0.25	ns
C _{IN}	Input capacitance	$V_I = 0 V \text{ or } V_{CC}$	4.5	pF
C _{OUT}	Output capacitance	Outputs disabled; $V_O = 0 V \text{ or } V_{CC}$	11.5	pF
r _{on}	A1 to A2	$V_{CC} = 5.5 \text{ V}; \text{ V}_{I} = 0 \text{ V}$	5	Ω

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	ORDER CODE	DWG NUMBER
56-Pin Plastic SSOP	–40 to +85 °C	CBTD16212DL	SOT371-1
56-Pin Plastic TSSOP	–40 to +85 °C	CBTD16212DGG	SOT364-1

NOTE:

1. Standard packing quantities and other packaging data is available at www.philipslogic.com/support/packages.

FUNCTION TABLE

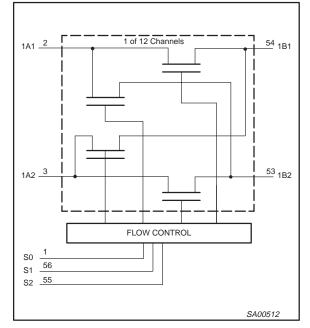
S2	S1	S0	A1	A2	FUNCTION
L	L	L	Z	Z	Disconnect
L	L	Н	B1	Z	A1 = B1
L	Н	L	B2	Z	A1 = B2
L	Н	Н	Z	B1	A2 = B1
Н	L	L	Z	B2	A2 = B2
Н	L	Н	Z	Z	Disconnect
Н	Н	L	B1	B2	A1 = B1, A2 = B2
Н	Н	Н	B2	B1	A1 = B2, A2 = B1

H = High voltage level

L = Low voltage level

Z = High impedance "off" state

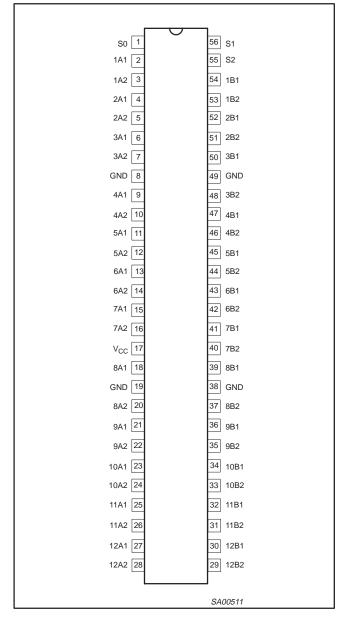
LOGIC SYMBOL



Product data

CBTD16212

PIN CONFIGURATION



PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 56, 55	S0, S1, S2	Data select
2, 4, 6, 9, 11, 13, 15, 18, 21, 23, 25, 27	1A1–12A1	A1 channel
3, 5, 7, 10, 12, 14, 16, 20, 22, 24, 26, 28	1A2–12A2	A2 channel
54, 52, 50, 47, 45, 43, 41, 39, 36, 34, 32, 30	1B1, 12B1	B1 channel
53, 51, 48, 46, 44, 42, 40, 37, 35, 33, 31, 29	1B2, 12B2	B2 channel
8, 19, 38, 49	GND	Ground (0 V)
17	V _{CC}	Positive supply voltage

CBTD16212

ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
I _{IK}	DC input diode current	V ₁ < 0	-50	mA
VI	DC input voltage ³		-0.5 to +7.0	V
V _{OUT}	DC output voltage ³	output in Off or High state	–0.5 to +5.5	V
I _{OUT}	DC output current	output in Low state	128	mA
T _{stg}	Storage temperature range		-65 to 150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL PARAMETER	PARAMETER	LIM	UNIT	
STWBOL	SOL FARAMETER	Min	Max	UNIT
V _{CC}	DC supply voltage	4.5	5.5	V
V _{IH}	High-level input voltage	2.0	_	V
V _{IL}	Low-level Input voltage	_	0.8	V
T _{amb}	Operating free-air temperature range	-40	+85	°C

DC ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETER	TEST CONDITIONS	T _{amb} = −40 to +85 °C			
			Min	Typ ¹	Max	1
V _{IK}	Input clamp voltage	$V_{CC} = 4.5 \text{ V}; I_I = -18 \text{ mA}$	—	—	-1.2	V
VP	Output high pass voltage	See Figure 1, page 6	—	—	-1.2	V
		$V_{CC} = 0 V; V_I = 5.5 V$	—	—	10	
	Input leakage current	V_{CC} = 5.5 V; V _I = GND or 5.5 V	—	—	±1	μA
I _{CC}	Quiescent supply current	V_{CC} = 5.5 V; I _O = 0, V _I = V _{CC} or GND	—	—	3.5	mA
ΔI _{CC}	Additional supply current per input pin ²	V_{CC} = 5.5 V, one input at 3.4 V, other inputs at V_{CC} or GND	_	_	2.5	mA
Cl	Control pins	V_{I} = 3 V or 0 V	—	4.5	—	pF
C _{IO(OFF)}	Port OFF capacitance	$V_{O} = 3 V \text{ or } 0 V; S0, S1, S2 = 0 V$	—	11.5	—	pF
		$V_{CC} = 4.5 \text{ V}; \text{ V}_1 = 0 \text{ V}; \text{ I}_1 = 64 \text{ mA}$	—	5	8	
r _{on} ³	r _{on} ³ A1 to A2	$V_{CC} = 4.5 \text{ V}; \text{ V}_1 = 0 \text{ V}; \text{ I}_1 = 30 \text{ mA}$	_	5	8	Ω
		V_{CC} = 4.5 V; V_1 = 2.4 V; I_I = 15 mA	—	16	35	

NOTES:

1. All typical values are at $V_{CC} = 5 \text{ V}$, $T_{amb} = 25 \text{ °C}$ 2. This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

3. Measured by the voltage drop between the A and the B terminals at the indicated current through the switch.

On-state resistance is determined by the lowest voltage of the two (A or B) terminals.

CBTD16212

Product data

AC CHARACTERISTICS

 $GND = 0 V; t_{R;} C_{L} = 50 pF$

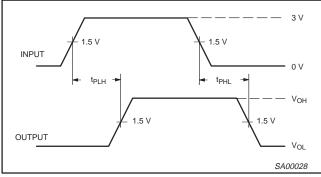
SYMBOL	PARAMETER	FROM (INPUT)	то	V_{CC} = 5.0 V ±0.5 V		UNIT	
STMBOL	FARAMETER		(OUTPUT)	Min	Max	UNIT	
t _{pd}	Propagation delay ¹	A or B	B or A	—	0.25	ns	
t _{en}	Output enable time to High and Low level	S	A or B	2	11.5	ns	
t _{dis}	Output disable time from High and Low level	S	A or B	1.5	8.5	ns	

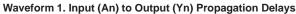
NOTE:

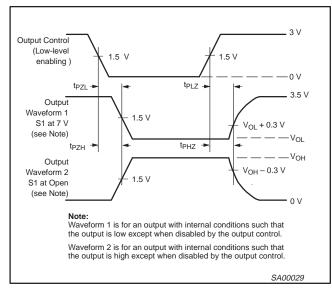
1. This parameter is warranted but not production tested. The propagation delay is based on the RC time constant of the typical on-state resistance of the switch and a load capacitance of 50 pF, when driven by an ideal voltage source (zero output impedance).

AC WAVEFORMS

 V_{M} = 1.5 V, V_{IN} = GND to 3.0 V

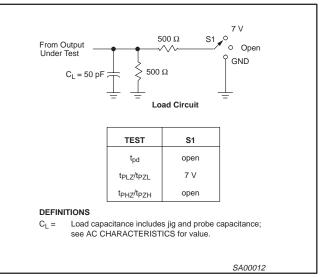






Waveform 2. 3-State Output Enable and Disable Times

TEST CIRCUIT AND WAVEFORMS



CBTD16212

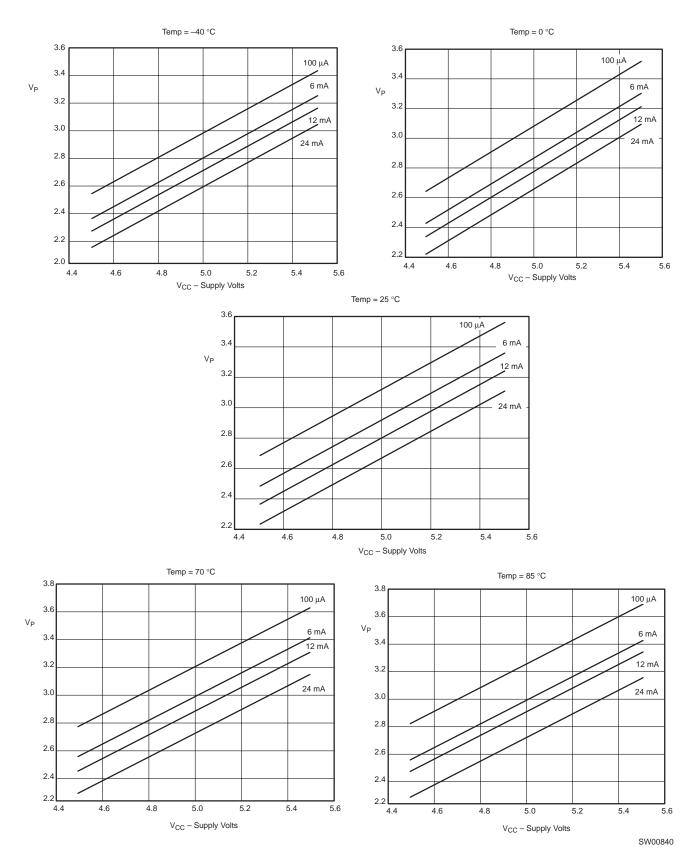
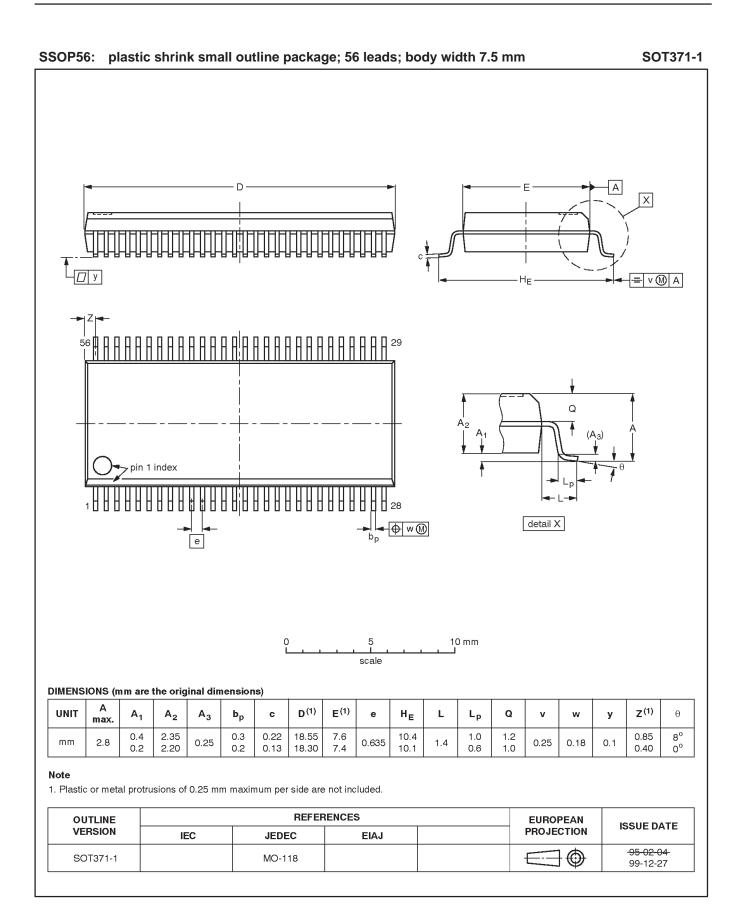
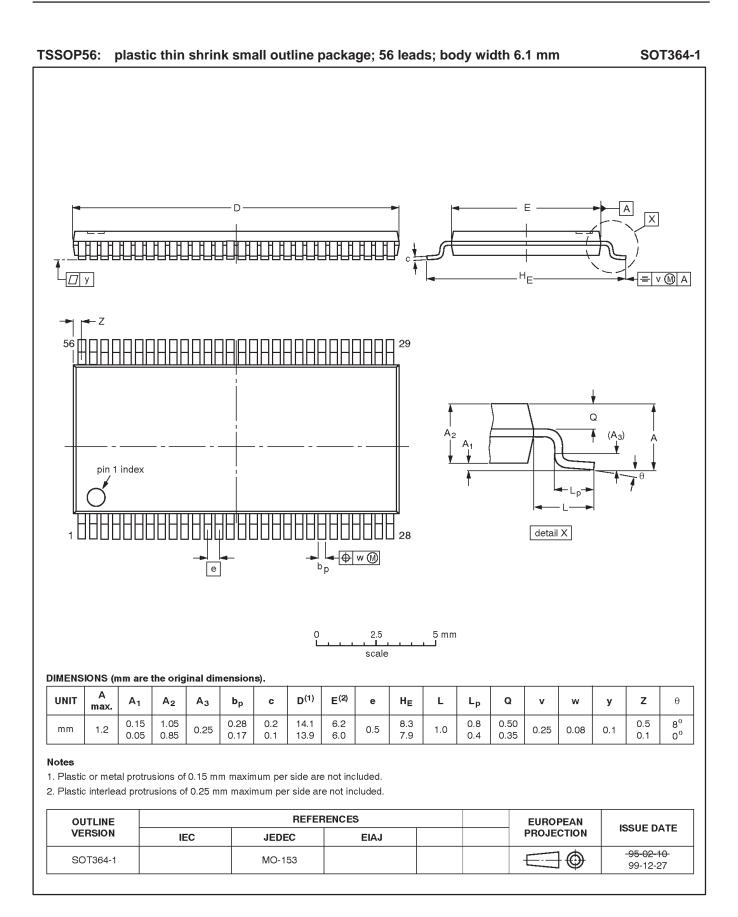


Figure 1. Typical characteristics

CBTD16212



CBTD16212



CBTD16212

NOTES

Data sheet status

Data sheet status ^[1]	Product status ^[2]	Definitions
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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